

26N40-HC

Power MOSFET

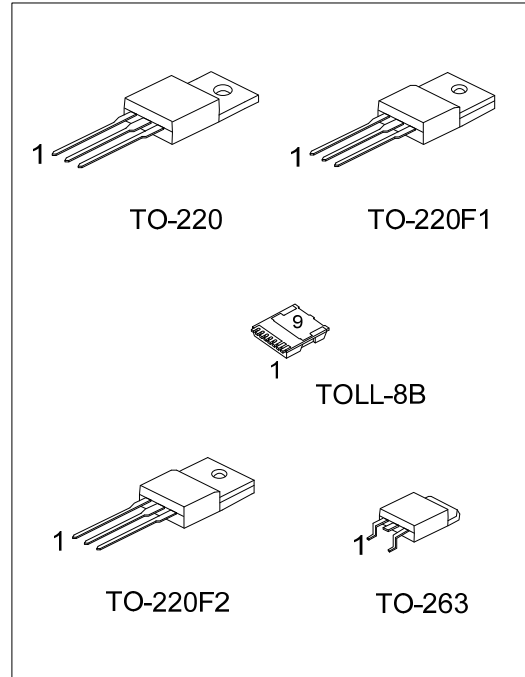
26A, 400V N-CHANNEL POWER MOSFET

DESCRIPTION

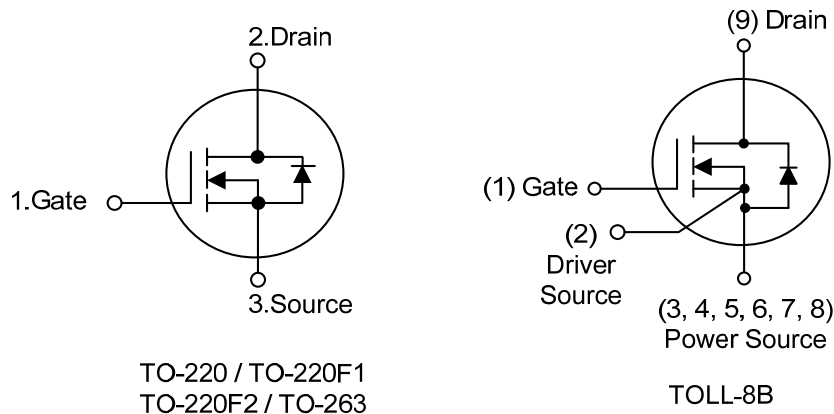
The UTC **26N40-HC** is a high voltage power MOSFET combines advanced planar MOSFET designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and high rugged avalanche characteristics. This power MOSFET is usually used in high speed switching applications of switching power supplies and adaptors.

FEATURES

- * $R_{DS(ON)} \leq 0.175 \Omega$ @ $V_{GS} = 10V$, $I_D = 12A$
- * Fast switching capability
- * Avalanche energy tested
- * Improved dv/dt capability, high ruggedness



SYMBOL



ORDERING INFORMATION

Ordering Number		Package	Pin Assignment									Packing
Lead Free	Halogen Free		1	2	3	4	5	6	7	8	9	
26N40L-HC-TA3-T	26N40G-HC-TA3-T	TO-220	G	D	S							Tube
26N40L-HC-TF1-T	26N40G-HC-TF1-T	TO-220F1	G	D	S	-	-	-	-	-	-	Tube
26N40L-HC-TF2-T	26N40G-HC-TF2-T	TO-220F2	G	D	S	-	-	-	-	-	-	Tube
26N40L-HC-TQ2-T	26N40G-HC-TQ2-T	TO-263	G	D	S	-	-	-	-	-	-	Tube
26N40L-HC-TQ2-R	26N40G-HC-TQ2-R	TO-263	G	D	S	-	-	-	-	-	-	Tape Reel
26N40L-HC-T8B-R	26N40G-HC-T8B-R	TOLL-8B	G	S	S	S	S	S	S	S	D	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

26N40G-HC-TA3-T (1) Packing Type (2) Package Type (3) Version Code (4) Green Package	(1) T: Tube, R: Tape Reel (2) TA3: TO-220, TF1: TO-220F1, TF2: TO-220F2, TQ2: TO-263, T8B: TOLL-8B (3) Version HC (4) G: Halogen Free and Lead Free, L: Lead Free
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MARKING

TO-220 / TO-220F1 / TO-220F2 / TO-263	TOLL-8B
UTC 26N40 HC □□□□ 1 Version Code ← HC Lot Code ← □□□□ Date Code → □□□□ L: Lead Free G: Halogen Free	UTC 26N40 HC □□□□ 1 Version Code ← HC Lot Code ← □□□□ Date Code → □□□□ L: Lead Free G: Halogen Free

■ ABSOLUTE MAXIMUM RATINGS ($T_c=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DS}	400	V
Gate-Source Voltage		V_{GS}	± 30	V
Continuous Drain Current		I_D	26	A
Pulsed Drain Current (Note 2)		I_{DM}	52	A
Avalanche Energy	Single Pulsed (Note 3)	E_{AS}	1440	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.2	V/ns
Power Dissipation	TO-220/TO-263	P_D	200	W
	TO-220F1/TO-220F2		42	W
	TOLL-8B		260	W
Junction Temperature		T_J	+150	$^{\circ}\text{C}$
Storage Temperature		T_{STG}	-55 ~ +150	$^{\circ}\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3. $L = 30\text{mH}$, $I_{AS} = 9.8\text{A}$, $V_{DD} = 50\text{V}$, $R_G = 25\ \Omega$, Starting $T_J = 25^{\circ}\text{C}$

4. $I_{SD} \leq 26\text{A}$, $di/dt \leq 200\text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DS}$, Starting $T_J = 25^{\circ}\text{C}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATING	UNIT
Junction to Ambient	TO-220/TO-220F1	θ_{JA}	62.5	$^{\circ}\text{C}/\text{W}$
	TO-220F2/TO-263			
	TOLL-8B		40	$^{\circ}\text{C}/\text{W}$
Junction to Case	TO-220/TO-263	θ_{JC}	0.625	$^{\circ}\text{C}/\text{W}$
	TO-220F1/TO-220F2		2.97	$^{\circ}\text{C}/\text{W}$
	TOLL-8B		0.48 (Note)	$^{\circ}\text{C}/\text{W}$

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

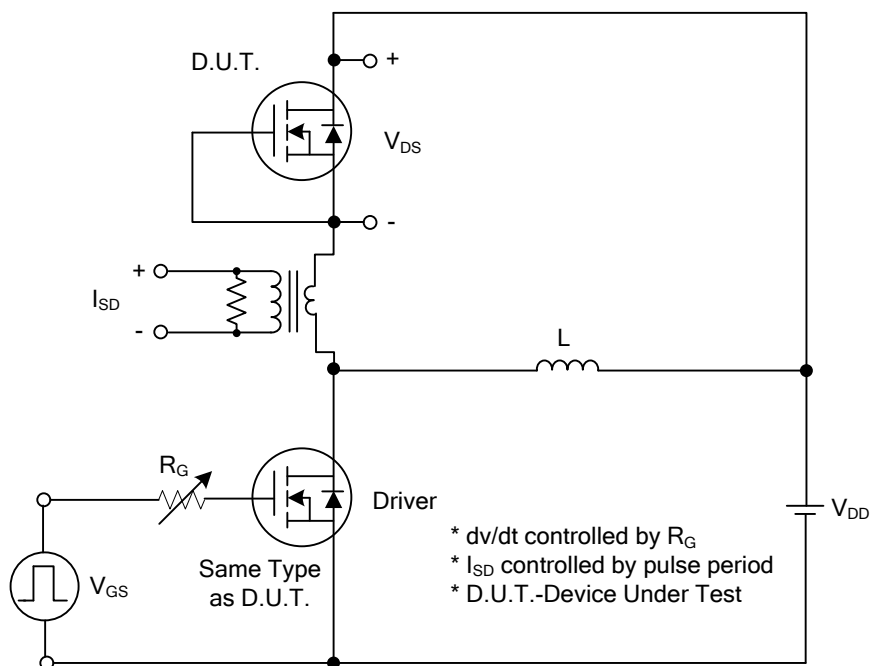
■ ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	V _{GS} =0V, I _D =250μA	400			V
Drain-Source Leakage Current		I _{DSS}	V _{DS} =400V, V _{GS} =0V			10	μA
Gate- Source Leakage Current	Forward	I _{GSS}	V _{GS} =30V, V _{DS} =0V			100	nA
	Reverse		V _{GS} =-30V, V _{DS} =0V			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250μA	2.8		4.0	V
Static Drain-Source On-State Resistance		R _{DS(ON)}	V _{GS} =10V, I _D =12A			0.175	Ω
DYNAMIC CHARACTERISTICS							
Input Capacitance		C _{ISS}	V _{DS} =25V, V _{GS} =0V, f=1.0MHz		2800		pF
Output Capacitance		C _{OSS}			345		pF
Reverse Transfer Capacitance		C _{RSS}			28		pF
SWITCHING CHARACTERISTICS							
Total Gate Charge (Note 1)		Q _G	V _{DS} =320V, V _{GS} =10V, I _D =26A (Note 1, 2)		70		nC
Gate-Source Charge		Q _{GS}			20		nC
Gate-Drain Charge		Q _{GD}			22		nC
Turn-On Delay Time (Note 1)		t _{D(ON)}	V _{DS} =100V, V _{GS} =10V, I _D =26A, R _G =25Ω (Note 1, 2)		36		ns
Turn-On Rise Time		t _R			28		ns
Turn-Off Delay Time		t _{D(OFF)}			210		ns
Turn-Off Fall Time		t _F			42		ns
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS							
Maximum Body-Diode Continuous Current		I _S				26	A
Maximum Body-Diode Pulsed Current		I _{SM}				48	A
Drain-Source Diode Forward Voltage (Note 1)		V _{SD}	I _S =26A , V _{GS} =0V			1.4	V
Reverse Recovery Time (Note 1)		t _{rr}	I _S =26A , V _{GS} =0V		390		ns
Reverse Recovery Charge		Q _{rr}	di/dt=100A/μs		11.5		μC

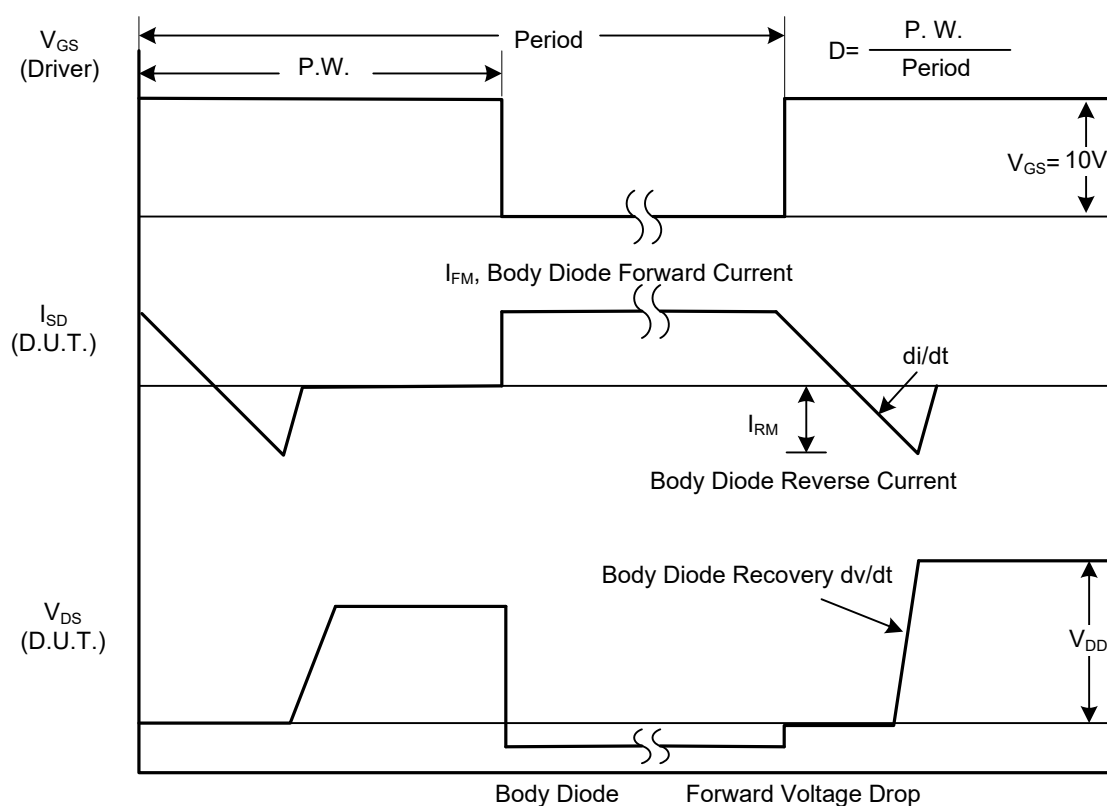
Notes: 1. Pulse Test: Pulse width ≤ 300μs, Duty cycle ≤ 2%.

2. Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS

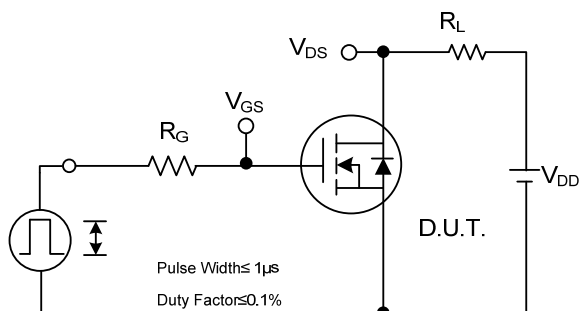


Peak Diode Recovery dv/dt Test Circuit

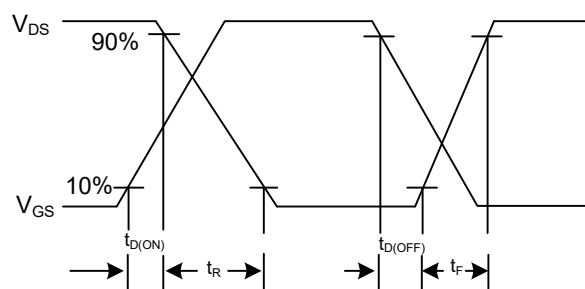


Peak Diode Recovery dv/dt Waveforms

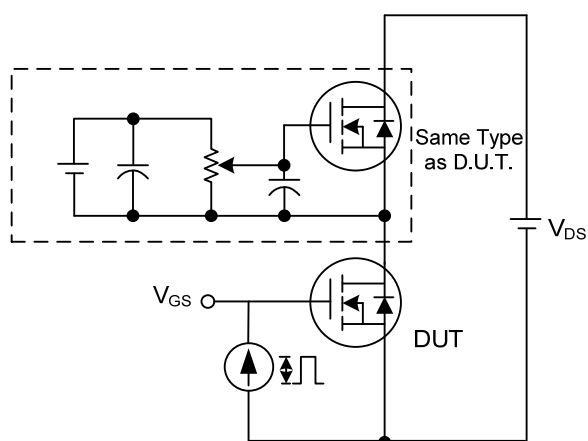
■ TEST CIRCUITS AND WAVEFORMS



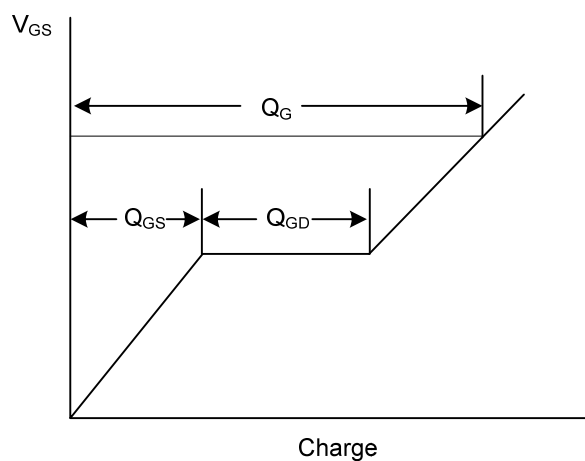
Switching Test Circuit



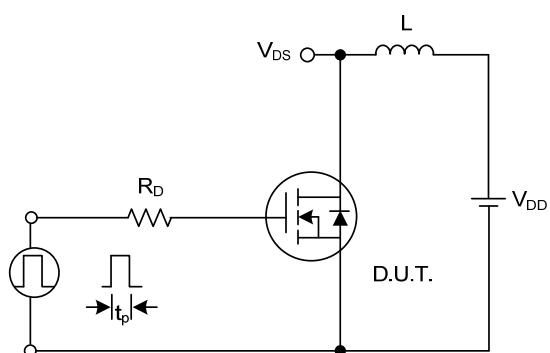
Switching Waveforms



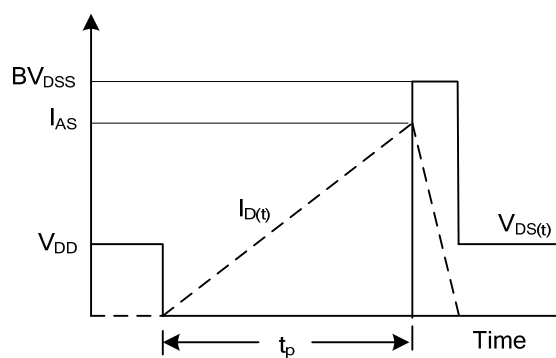
Gate Charge Test Circuit



Gate Charge Waveform

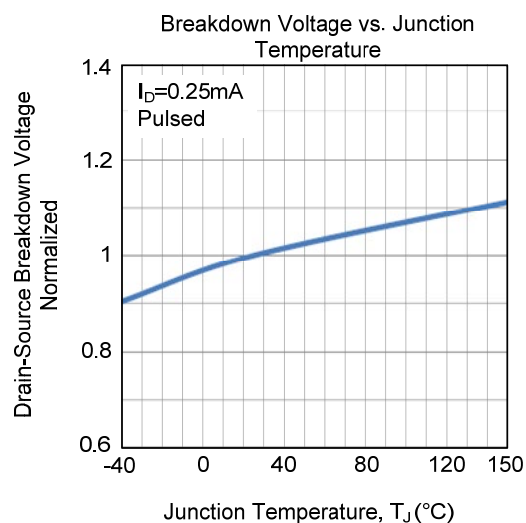
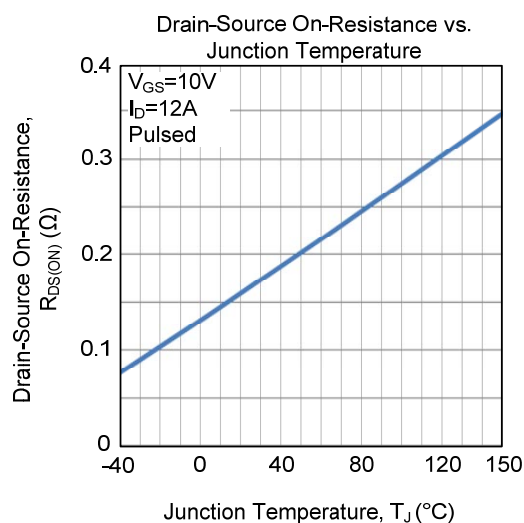
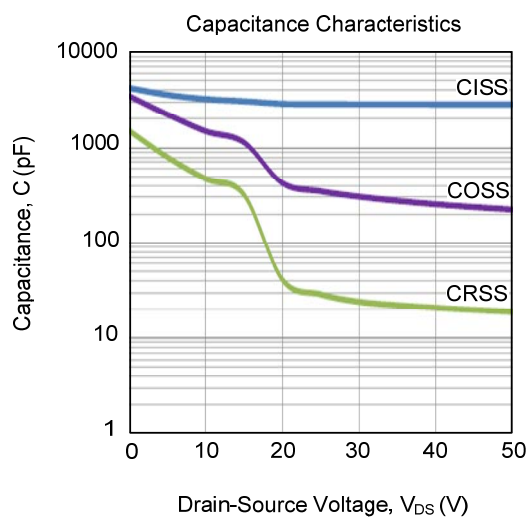
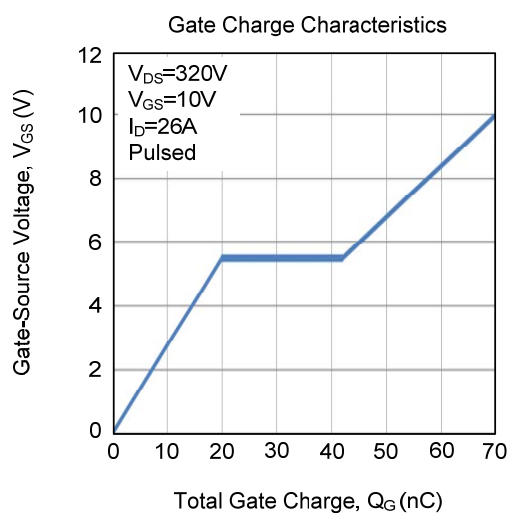
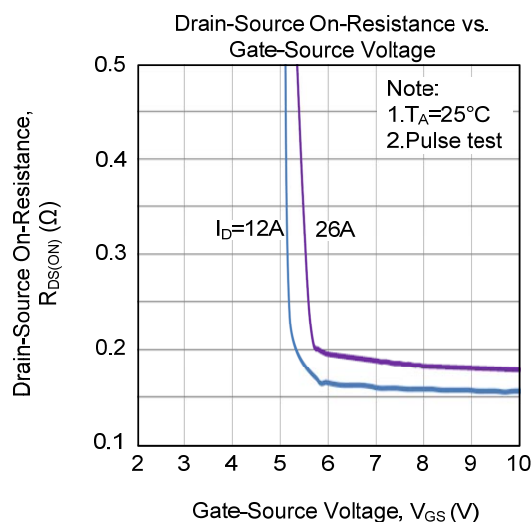
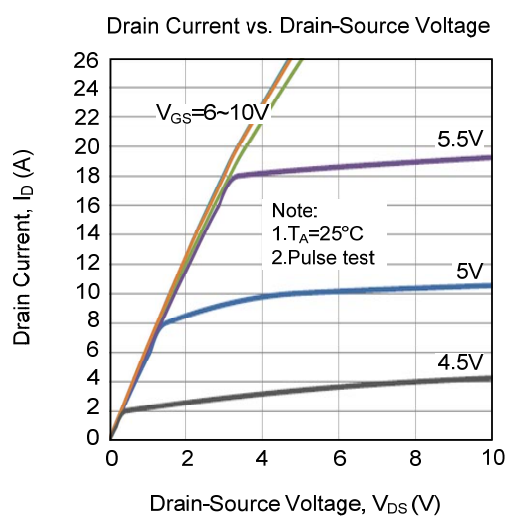


Unclamped Inductive Switching Test Circuit

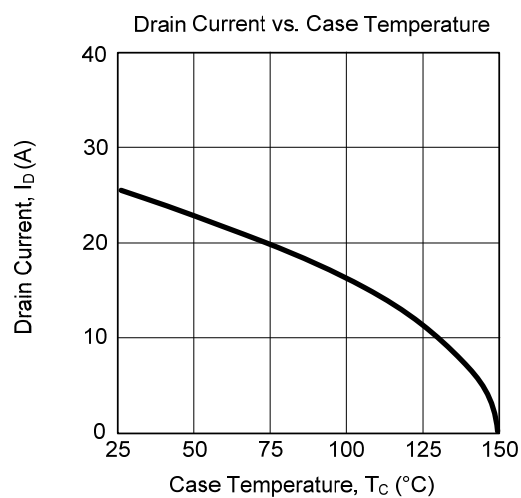
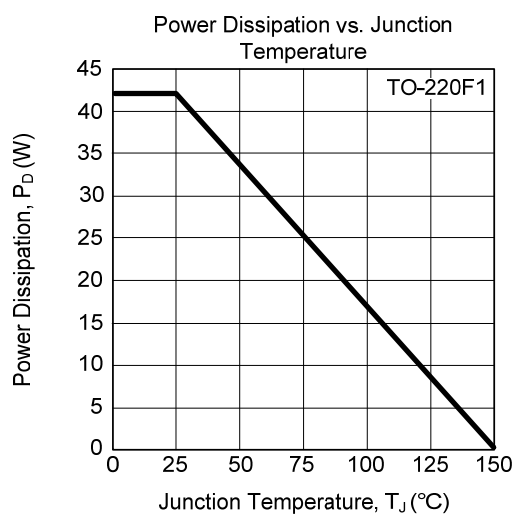
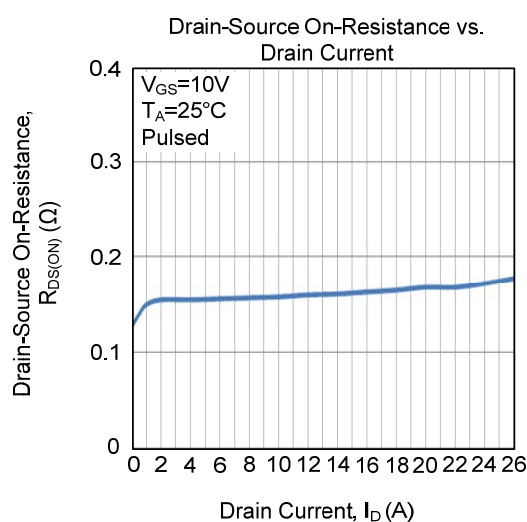
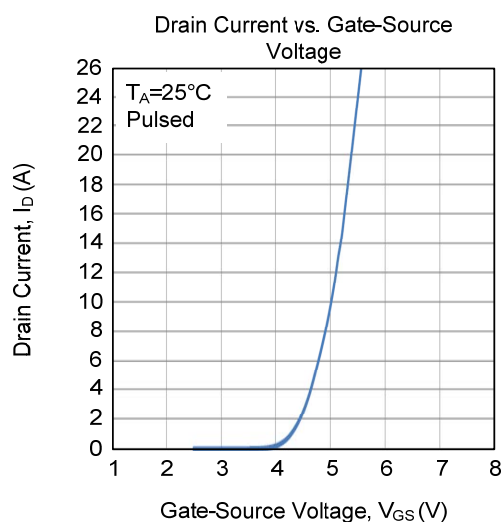
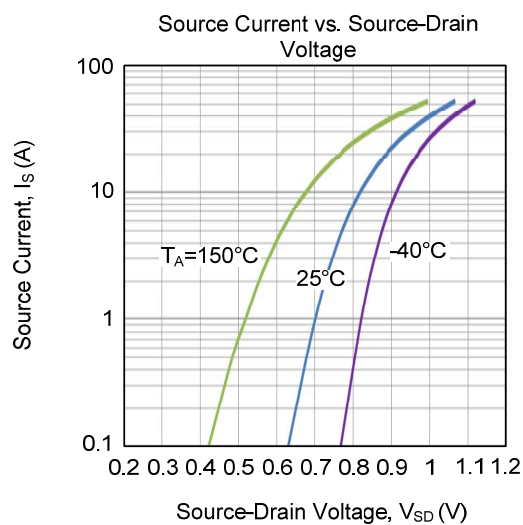
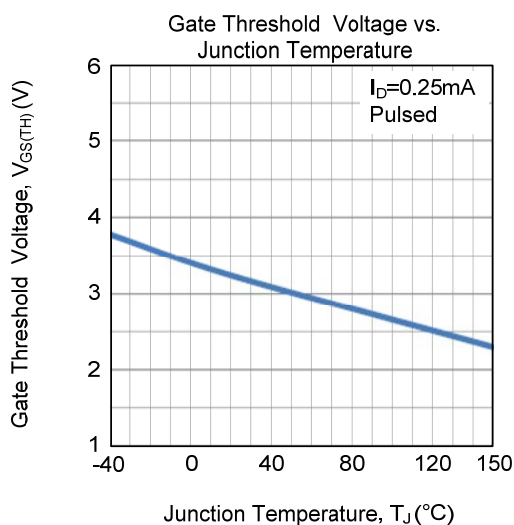


Unclamped Inductive Switching Waveforms

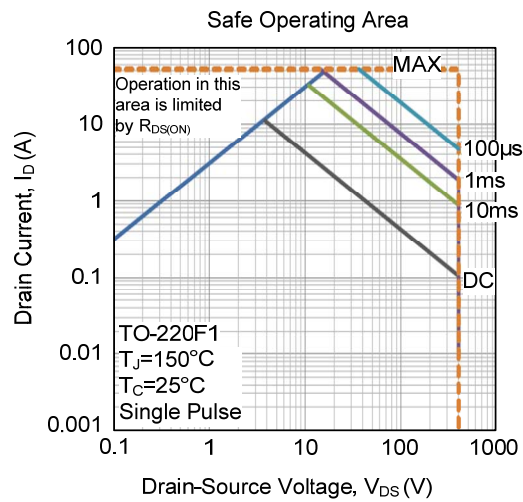
TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



■ TYPICAL CHARACTERISTICS (Cont.)



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